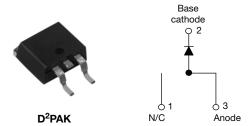




Vishay High Power Products

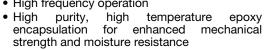
Schottky Rectifier, 10 A



PRODUCT SUMMARY						
I _{F(AV)}	10 A					
V_{R}	35 V/45 V					
I _{RM}	15 mA at 125 °C					

FEATURES

- 150 °C T_J operation
- TO-220 and D²PAK packages
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Halogen-free according to IEC 61249-2-21 definition
- Compliant to RoHS directive 2002/95/EC
- AEC-Q101 qualified

DESCRIPTION

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	10	۸					
I _{FRM}	T _C = 135 °C	20	Α					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	1060	A					
V _F	10 Apk, T _J = 125 °C	0.57	V					
T _J	Range	- 65 to 150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRB1035PbF	UNITS					
Maximum DC reverse voltage	V_{R}	35	45	V				
Maximum working peak reverse voltage	V_{RWM}	33	45	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	T _C = 135 °C, rated V _R		10				
Peak repetitive forward current	I _{FRM}	Rated V _R , square wave, 20 k	kHz, T _C = 135 °C	20				
Non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	Α			
		Surge applied at rated load single phase, 60 Hz	150					
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 4 \text{n}$	8	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А			

VS-MBRB1035PbF, VS-MBRB1045PbF

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		20 A	T _J = 25 °C	0.84	V			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _{.1} = 125 °C	0.57				
		20 A	1J = 125 C	0.72				
Maximum instantaneous reverse	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA			
current		T _J = 125 °C	hated DC voltage	15				
Threshold voltage	V _{F(TO)}	T. T. marvingues		0.354	V			
Forward slope resistance	r _t	ij = ijiliaxiiliulii	$T_J = T_J$ maximum		mΩ			
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range	600	pF				
Typical series inductance	L _S	Measured from top of ter	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction tempera	ture range	TJ	TJ		°C		
Maximum storage tempera	ture range	T _{Stg}		- 65 to 175	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.0	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased (Only for TO-220)	0.50	C/VV		
Approximate weight				2	g		
				0.07	OZ.		
minimui				6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf \cdot in)		
Marking device			Case style D ² PAK	MBRE	31035		
			Case style D-PAN	MBRE	31045		



Schottky Rectifier, 10 A Vishay High Power Products

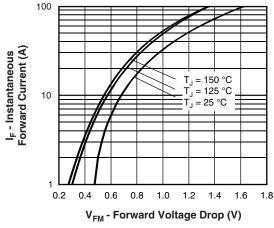


Fig. 1 - Maximum Forward Voltage Drop Characteristics

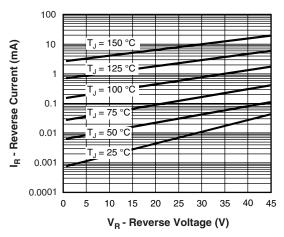


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

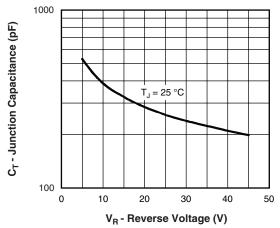


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

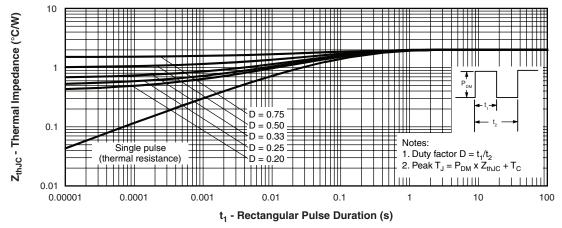


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Vishay High Power Products Schottky Rectifier, 10 A



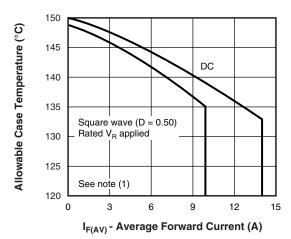


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

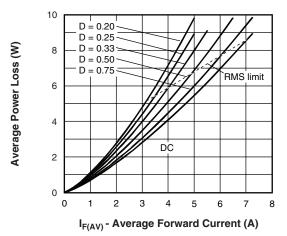


Fig. 6 - Forward Power Loss Characteristics

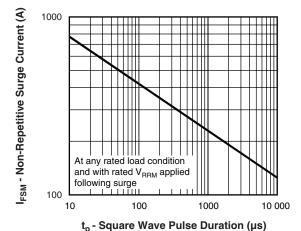


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = Rated V_R$

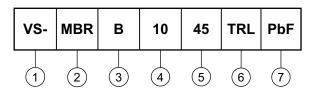


VS-MBRB1035PbF, VS-MBRB1045PbF

Schottky Rectifier, 10 A Vishay High Power Products

ORDERING INFORMATION TABLE

Device code



- 1 HPP product suffix
- 2 Essential part number
- 3 B = Surface mount
- Current rating (10 = 10 A)
 - Voltage ratings 35 = 35 V 45 = 45 V
- 6 • None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 7 PbF = Lead (Pb)-free

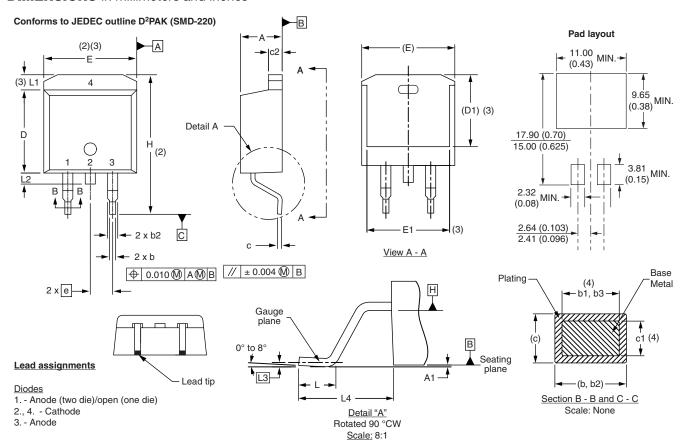
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					
SPICE model	www.vishay.com/doc?95293					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346
b1	0.51	0.89	0.020	0.035	4	e 2.54 BSC		BSC	0.100 BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB

NOTES

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2, 3

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Vishay

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